

Zibo Seno Electronic Engineering Co., Ltd.



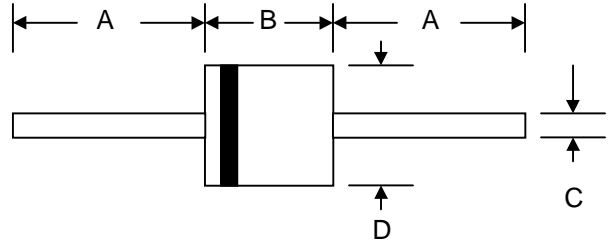
20SQ030-20SQ100



20A SCHOTTKY BARRIER DIODE

FEATURES

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability



Mechanical Data

- Case: R-6/P-600, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 2.1 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version**

R-6/P-600		
Dim	Min	Max
A	25.4	—
B	8.60	9.10
C	1.20	1.30
D	8.60	9.10
All Dimensions in mm		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	20SQ030	20SQ035	20SQ040	20SQ045	20SQ050	20SQ060	20SQ080	20SQ100	UNIT	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	30	35	40	45	50	60	80	100	V	
Maximum RMS Voltage	V _{RMS}	21	24.5	28	31.5	35	42	56	70	V	
Maximum DC Blocking Voltage	V _{DC}	30	35	40	45	50	60	80	100	V	
Maximum Average Forward Rectified Current@T _c =95 °C	I _(AV)	20								A	
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load(JEDEC Method)	I _{FSM}	275								A	
Peak Forward Voltage at 20A DC(Note1)	V _F	0.55			0.70		0.95			V	
Maximum DC Reverse Current @T _j =25°C at Rated DC Bolcking Voltage @T _j =100°C	I _R	0.5				50					mA
Tyical Junction Capacitance (Note2)	C _J	450								PF	
Tyical Thermal Resistance (Note3)	R _J	3.0								°C/w	
Operating Temperature Range	T _J	-55 to+200								°C	
Storage Temperature Range	T _{STG}	-55 to+200								°C	

NOTES:1.300us Pulse Width, 2%Dudy Cycle.

2.Measured at 1.0 MHZ and applied reverse voltage of 4.0VDC.

3.Thermal Resistance Junction to Case.

FIG.1-FORWARD CURRENT DERATING CURVE

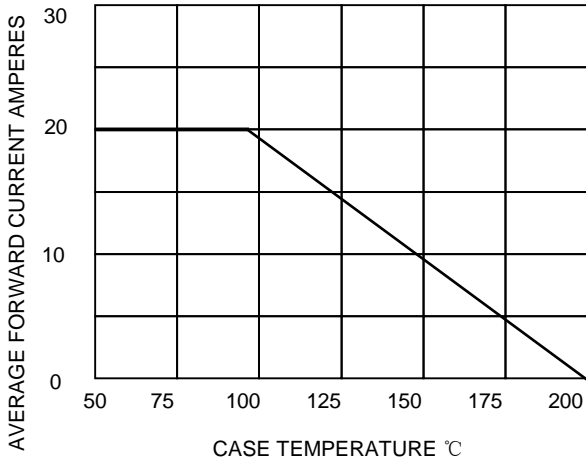


FIG.2-MAXIMUM NON-REPETITIVE SURGE

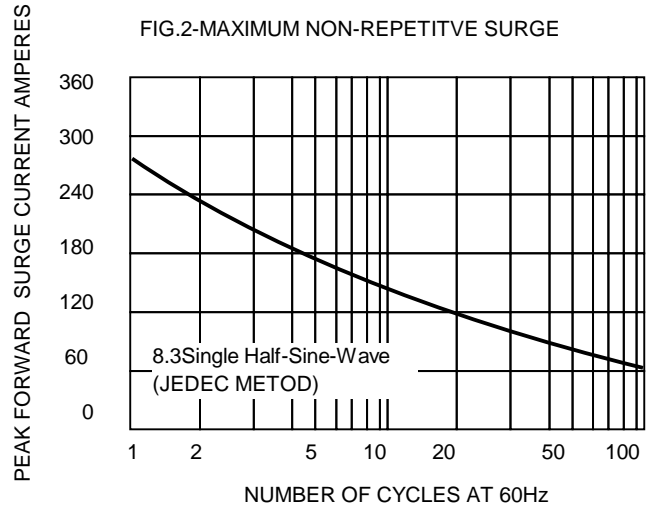


FIG.3-TYPICAL REVERSE CHARACTERISTICS

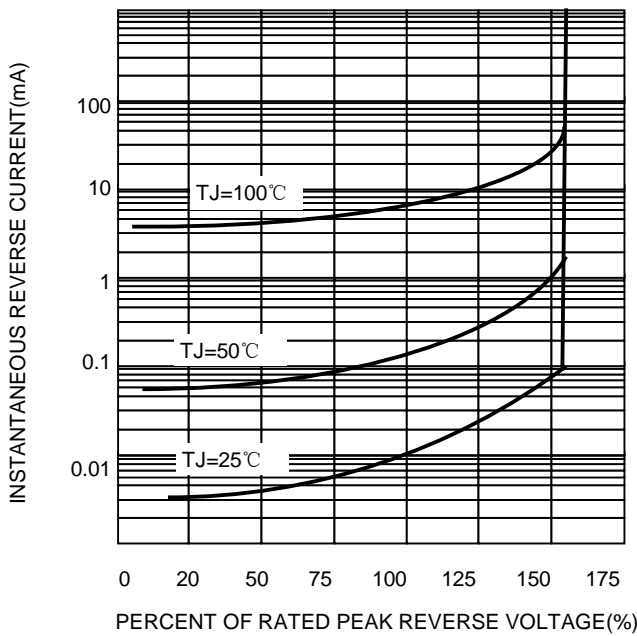


FIG.4-TYPICAL FORWARD CHARACTERISTICS

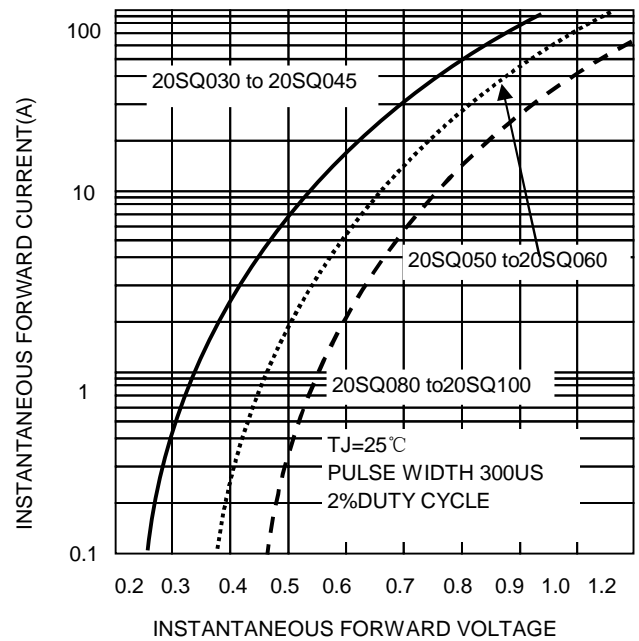


FIG.5-TYPICAL JUNCTION CAPACITANCE

